

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:
SPENCER, GREGORY S.

Application No.: 10/659885

Filed: 09-11-2003

Title: INTEGRATION OF ULTRA LOW K DIELECTRIC IN A SEMICONDUCTOR
FABRICATION PROCESS

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Patent No.: 6992003 B2

Issue Date: 1/31/2006

Examiner: George A. Goudreau

Group Art Unit: 1765

Docket No.: SC12765TP

Certificate of Submission

I hereby certify that this correspondence is being submitted to the
USPTO, Alexandria, VA.

- ☐ Addressed per C.F.R. § 1.1(a) and deposited with the United
States Postal Service with sufficient postage as first class mail.
- ☐ Facsimile transmitted in accordance with C.F.R. §1.6(d).
- ☒ Submitted electronically via EFS in accordance with "Legal
Framework for EFS Web".

March 7, 2008
Date of Submission

Teresa Shephard
Signature

Teresa Shephard
Printed Name of Person Signing Certificate

Commissioner for Patents
Alexandria, VA 22313

SUBMISSION OF CERTIFICATE OF CORRECTION

Dear Commissioner:

Enclosed is a Certificate of Correction listing error(s) in the subject patent. Please enter
these corrections. Since at least some of the errors appear to be on the part of the Applicant,
the required fee may be charged to Deposit Account 503079 via the Electronic Filing System.

March 7, 2008
Date

Respectfully submitted,

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CERTIFICATE OF CORRECTION**Page 1 of 1

PATENT NO.: 6992003 B2
APPLICATION NO: 10/659885
DATE: 09-11-2003
FIRST NAMED INVENTOR: SPENCER, GREGORY S.

It is certified that error appears in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

In Column 6, Line 20, Claim No. 1:

Change "dielectric including reducing a flaw rate" to--dielectric including reducing a flow rate--

In Column 7, Line 9, Claim No. 11:

Change "comprises an precursor selected" to--comprises a precursor selected--

In Column 7, Line 18, Claim No. 13:

Change "further wherein an radio frequency power" to--further wherein a radio frequency power--

In Column 7, Line 27, Claim No. 14:

Change "a second dielectric overlying, the first" to--a second dielectric overlying the first--

In Column 8, Line 7, Claim No. 17:

Change "wherein The organic" to--wherein the organic--

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